TOSHIBA Thyristor Silicon Planar Type

# S 6 A 1 3

### **Condenser Discharge Control Applications**

- FWD included between cathode and anode
- Critical rate of rise of ON-state current:  $di/dt = 750 \text{ A/}\mu\text{s}$
- Repetitive peak surge ON-state current:  $ITRM = 500 \text{ A} (t_W = 2 \mu s)$
- Repetitive peak OFF-state voltage:  $V_{DRM} = 800 \text{ V}$
- Gate trigger current: IGT = 30 mA max.

#### **Maximum Ratings**

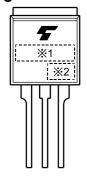
Characteristics	Symbol	Rating	Unit	
Repetitive peak OFF-state voltage	$V_{DRM}$	800	V	
Repetitive peak surge ON-state current (Note)	I <sub>TRM</sub>	500	Α	
Repetitive peak surge forward current	I <sub>FRM</sub>	500	А	
(Note)				
Critical rate of rise of ON-state current	di/dt	750	A/μs	
(Note)	ai, at	7.00	γιμο	
Peak gate power dissipation	$P_{GM}$	5	W	
Average gate power dissipation	P <sub>G (AV)</sub>	0.5	W	
Peak forward gate voltage	$V_{FGM}$	10	V	
Peak reverse gate voltage	$V_{RGM}$	<b>–</b> 5	V	
Peak forward gate current	I <sub>GM</sub>	2	Α	
Junction temperature	Tj	-40~125	°C	
Storage temperature range	T <sub>stg</sub>	-40~150	°C	

1.4MAX 1.6MAX 1.

Weight: 1.5g (Typ.)

Note:  $V_D \le 0.8 \times rated$ ,  $Tc = 85^{\circ}C$ ,  $i_{gp} \ge 60$  mA,  $t_{gw} \ge 10$   $\mu s$ ,  $t_{gr} \le 150$  ns

### Marking



<b>※</b> 1	MARK	S6A13	TYPE NAME	S6A13		
X2  Lot Number  Month (starting from alphabet A)  Year (last decimal digit of the current year)						

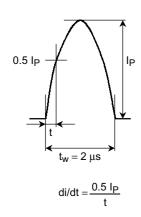
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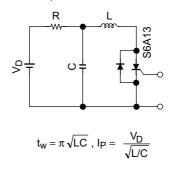
## **Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Repetitive peak OFF-state current	I <sub>DRM</sub>	V <sub>DRM</sub> = Rated	_	_	10	μΑ
Peak ON-state voltage (thyristor)	V <sub>TM</sub>	I <sub>TM</sub> = 25 A	_	_	1.5	V
Peak forward voltage (diode)	V <sub>FM</sub>	I <sub>FM</sub> = 25 A	_	_	2.0	V
Gate trigger voltage	V <sub>GT</sub>	V CV D 40 O	_	_	1.0	V
Gate trigger current	I <sub>GT</sub>	$V_D = 6 \text{ V}, R_L = 10 \Omega$	_	_	30	mA
Gate non-trigger voltage	$V_{GD}$	V <sub>D</sub> = Rated, Tc = 125°C	0.2	_	_	V
Critical rate of rise of OFF-state voltage	dv/dt	V <sub>DRM</sub> = Rated, Tc = 125°C Exponential Rise	_	50	_	V/μs
Holding current	lΗ	V <sub>D</sub> = 6 V, I <sub>TM</sub> = 1 A	_	_	35	mA
Thermal resistance (junction to ambient)	R <sub>th (j-a)</sub>	DC	_	_	70	°C/W

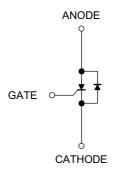
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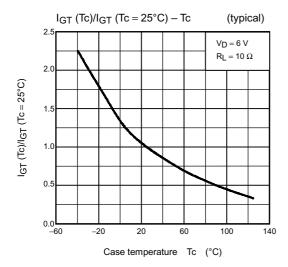


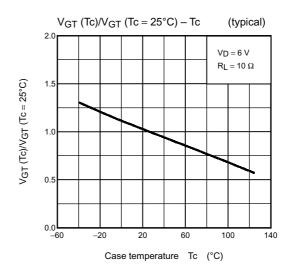
Test Circuit Examples

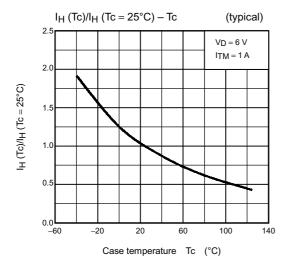


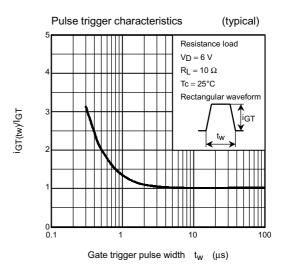
## **Equivalent Circuit**

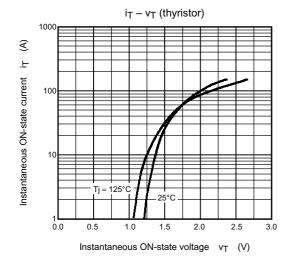


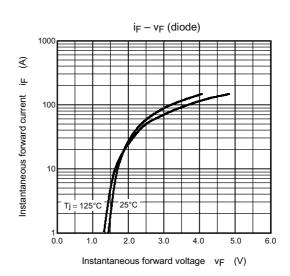












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